

LOW VOLTAGE SCHOTTKY RECTIFIER

Features

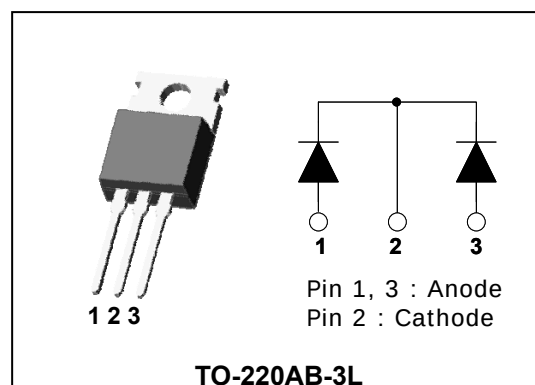
- Low forward voltage drop and leakage current
- Low power loss and High efficiency
- Guard-ring for overvoltage protection
- Dual common cathode rectifier
- Full lead (Pb)-free and RoHS compliant device

Applications

- Power supply - Output rectification
- High efficiency SMPS
- Free-wheeling diode
- Reverse battery protection
- DC to DC systems

Description

Schottky barrier rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptors and on board DC to DC converters.



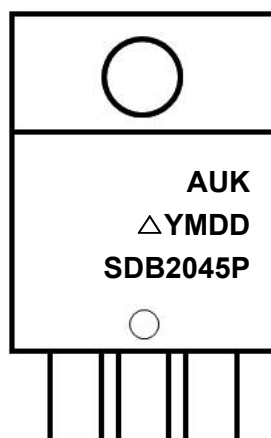
Product Characteristics

$I_{F(AV)}$	2 X 10A
V_{RRM}	45V
V_{FM} at 125 °C	0.50V
I_{FSM}	120A

Ordering Information

Device	Marking Code	Package	Packaging
SDB2045P	SDB2045P	TO-220AB-3L	Tube

Marking Information



AUK = Manufacture Logo

Δ = Control Code of Manufacture

YMDD = Date Code Marking

- Y = Year Code

- M = Monthly Code

- DD = Daily Code

SDB2045P = Specific Device Code

Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V_{RRM} V_{RWM} V_R	45	V
Maximum average forward rectified current	per diode	$I_{F(AV)}$	10	A
	total device		20	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I_{FSM}	120	A
Storage temperature range		T_{stg}	-45 to +150	°C
Maximum operating junction temperature		T_J	150	

Thermal Characteristics

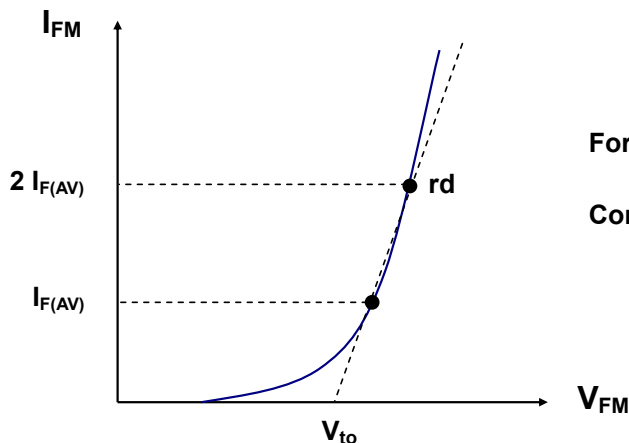
Characteristic		Symbol	Value	Unit
Maximum thermal resistance junction to case	per diode	$R_{th(j-c)}$	3.0	°C/W
	total device		2.8	

Electrical Characteristics (Per Diode)

Characteristic	Symbol	Test Condition		Min.	Typ.	Max.	Unit
Peak forward voltage drop	$V_{FM}^{(1)}$	$I_{FM} = 10A$	$T_J = 25^\circ C$	-	-	0.54	V
			$T_J = 125^\circ C$	-	-	0.50	
Reverse leakage current	$I_{RM}^{(1)}$	$V_R = V_{RRM}$	$T_J = 25^\circ C$	-	-	1.5	mA
			$T_J = 125^\circ C$	-	-	150	
Junction capacitance	C_j	$V_R = 5V_{DC}, f=1MHz$		-	550	-	pF

Note : (1) Pulse test : $t_p \leq 380\mu s$, Duty cycle $\leq 2\%$

To evaluate the conduction losses use the following equation (Fig 4.) : $P_F = 0.35 \times I_{F(AV)} + 0.015 I_{F(RMS)}^2$



Forward Voltage : $V_{FM} = V_{to} + rd I_{FM}$

Conduction Loss : $P_F = V_{to} I_{F(AV)} + rd I_{F(RMS)}^2$

Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics (Per diode)

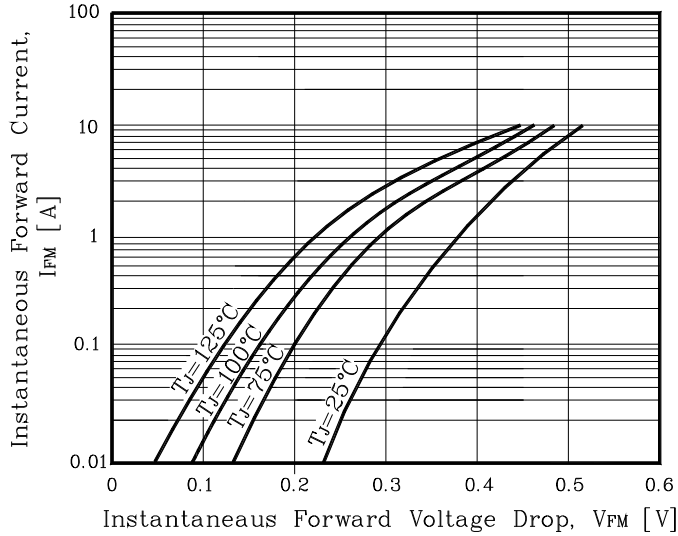


Fig. 2) Typical Reverse Characteristics (Per diode)

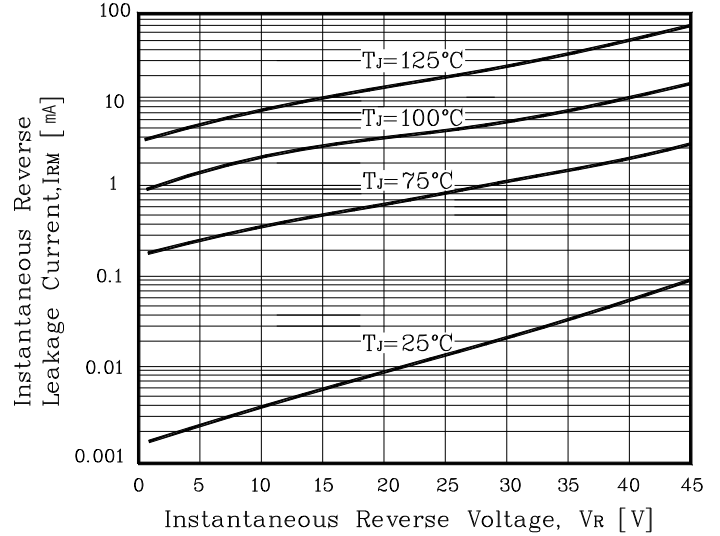


Fig. 3) Maximum Forward Derivative Curve

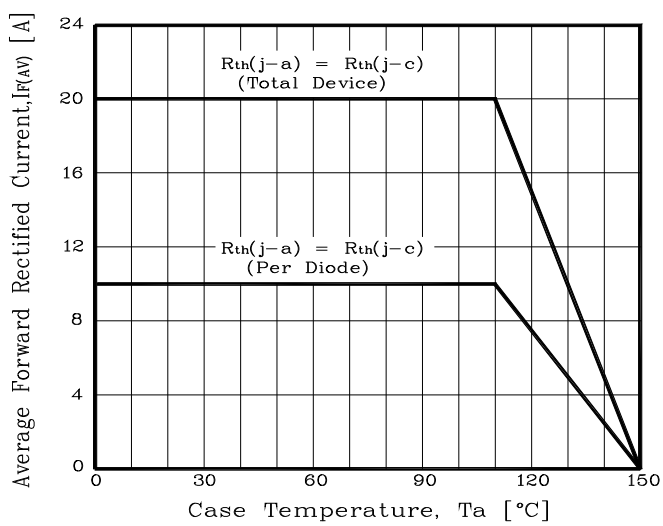


Fig. 4) Forward Power Dissipation (Per diode)

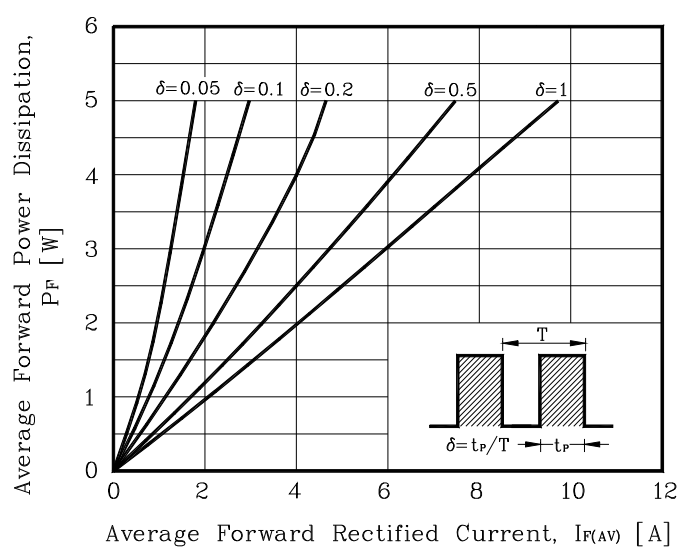


Fig. 5) Maximum Non-Repetitive Peak Forward Surge Current (Per diode)

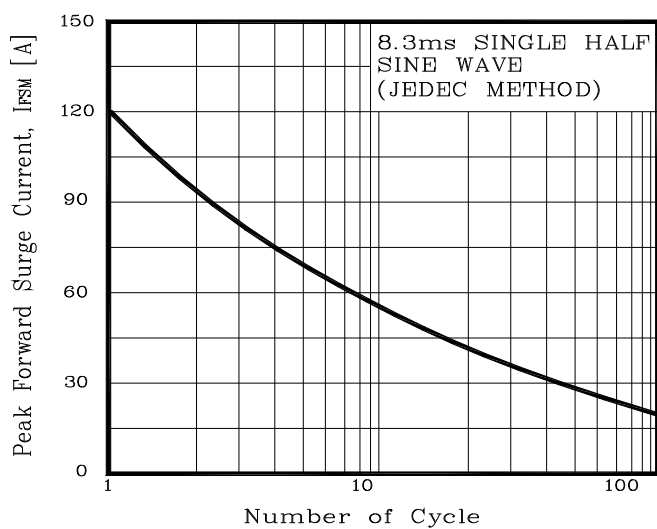
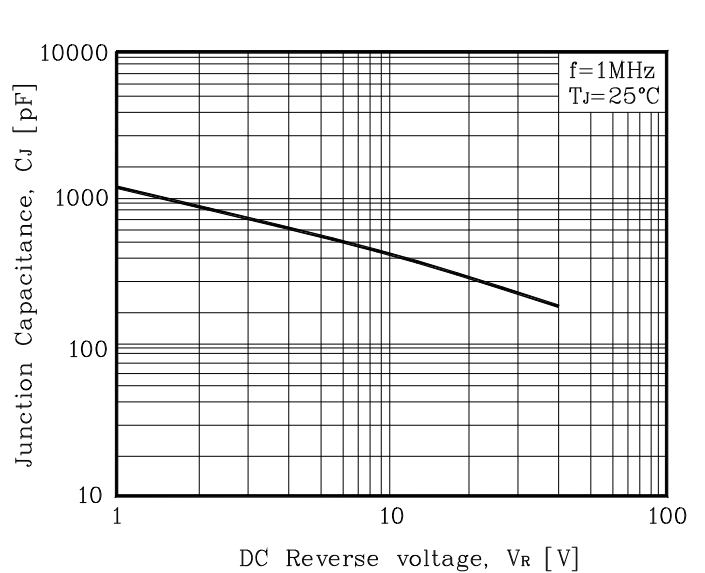
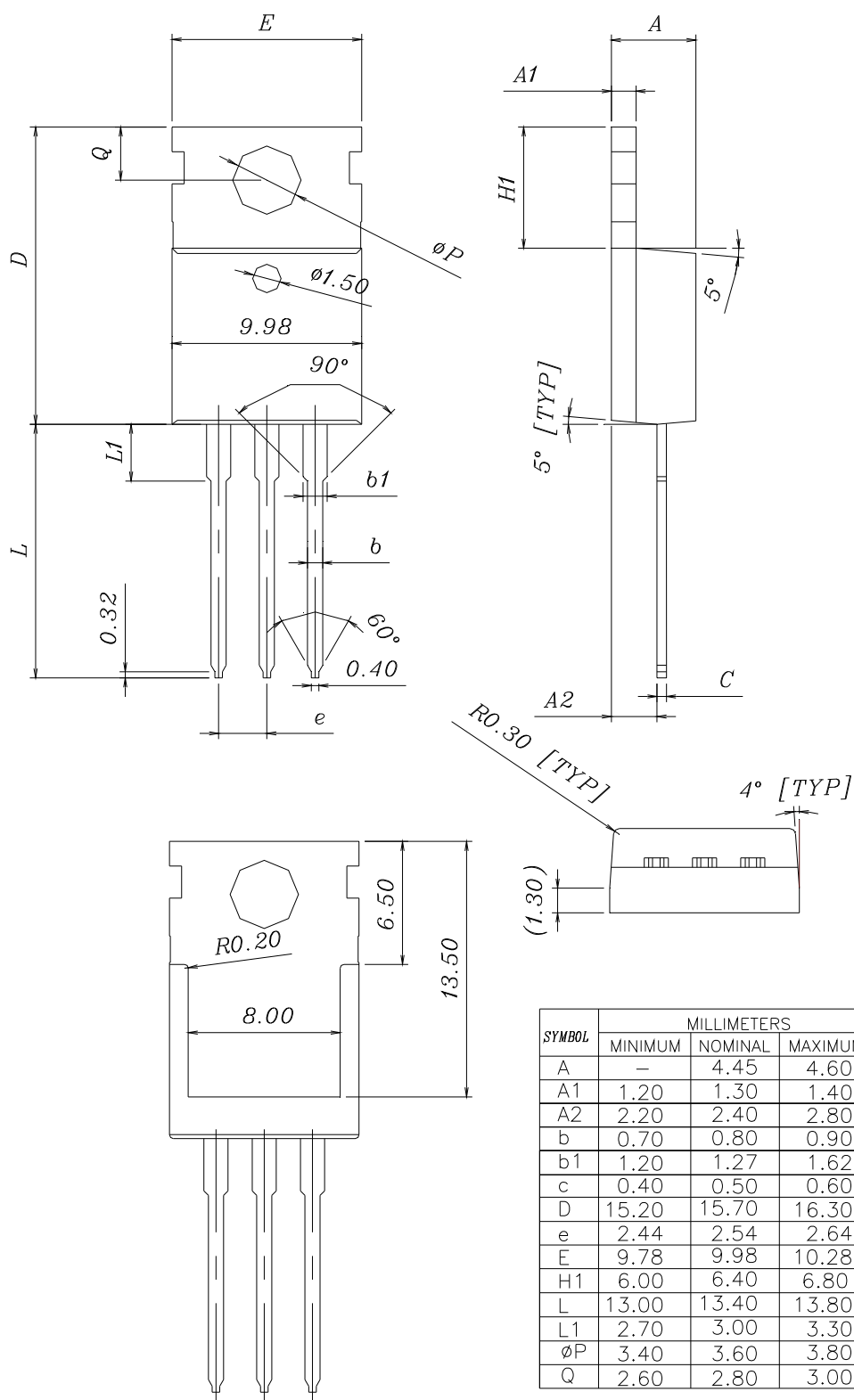


Fig. 6) Typical Junction Capacitance (Per diode)



Package Outline Dimension



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